

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT: Marsman, A. W. Attn. Doc. No.: NL031501US1
SERIAL NO.: 10/584,041 EXAMINER: Hu, Shouxiang
FILED: June 21, 2006 ART UNIT: 2811
CONFIRMATION No.: 6981

FOR: ***Method for the Manufacture of a Non-Volatile Ferroelectric Memory
Device and Memory Device Thus Obtained***

Mail Stop: Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Dear Sir:

In response to the Office Action dated January 14, 2010, the Applicant hereby submits this paper within three (3) months (until **April 14, 2010**) of the mailing date of the Office Action, and requests amendment of the above-identified application as follows wherein:

Amendments made to the Claims begin on page 2, and
Remarks begin on page 6.